International **ICR** Rectifier AN INFINEON TECHNOLOGIES COMPANY

# IRS2007(S,M)PBF

# 200-V half-bridge gate driver IC with $V_{CC}$ & $V_{BS}$ UVLO

### Features

- Gate drive supplies up to 20 V per channel
- Undervoltage lockout for V<sub>CC</sub>, V<sub>BS</sub>
- 3.3 V, 5 V, 15 V input logic compatible
- Tolerant to negative transient voltage
- Designed for use with bootstrap power supplies
- Cross-conduction prevention logic
- Matched propagation delay for both channels
- Internal set deadtime
- High-side output in phase with HIN input
- Low-side output out of phase with LIN input
- -40°C to 125°C operating range
- 2 kV HBM ESD
- RoHS compliant

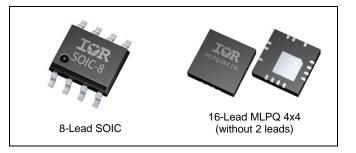
### Description

The IRS2007 is a high voltage, high speed power MOSFET and IGBT driver with dependent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3 V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver crossconduction. The floating channel can be used to drive an Nchannel power MOSFET or IGBT in the high side configuration which operates up to 200 V. Propagation delays are matched to simplify the HVIC's use in high frequency applications.

## **Product Summary**

Voffset	≤ 200 V
Vout	10 V – 20 V
I <sub>o+</sub> & I <sub>o-</sub> (typ.)	290 mA & 600 mA
t <sub>ON</sub> & t <sub>OFF</sub> (typ.)	160 ns & 150 ns
Deadtime (typ.)	520 ns

## **Package Options**

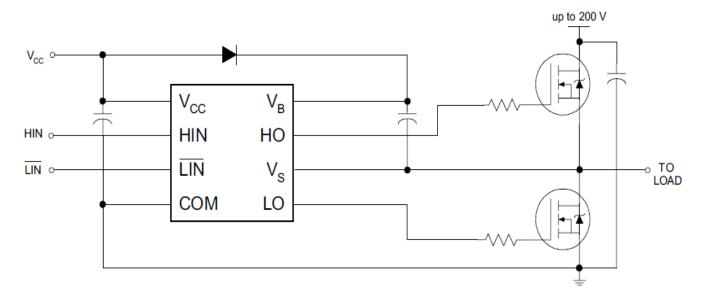


## **Typical Applications**

- Appliance motor drives, Stepper motor, Servo drives
- Micro inverter drives
- General purpose three phase inverters
- Light electric vehicles (e-bikes, e-scooters, e-toys)
- Wireless Charging
- General battery driven applications

Dees Dert Norther	Dealars Trees	Standard Pack		Standard Pack		Ondenskie Deut Normken
Base Part Number	Package Type	Form	Quantity	Orderable Part Number		
		Tape and Reel	2500	IRS2007STRPBF		
<u>IRS2007S</u>	8-Lead SOIC	Tube/Bulk	95	IRS2007SPBF		
<u>IRS2007M</u>	14-Lead MLPQ 4x4	Tape and Reel	3000	IRS2007MTRPBF		

## **Typical Connection Diagram**



(Refer to Lead Assignments for correct pin configuration). This diagram shows electrical connections only. Please refer tour Application Notes & DesignTips for proper circuit board layout.

## Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM unless otherwise stated in the table. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Definition		Max.	Units
Vcc	Low side supply voltage		-0.3	$25^{\dagger}$	
V <sub>IN</sub>	Logic input voltage (HIN & LIN)		COM - 0.3	V <sub>CC</sub> + 0.3	
VB	High-side floating well supply volta	ge	-0.3	225	
Vs	High-side floating well supply retur	n voltage	V <sub>B</sub> - 25	V <sub>B</sub> +0.3	V
V <sub>HO</sub>	Floating gate drive output voltage		Vs-0.3	V <sub>B</sub> +0.3	
VLO	Low-side output voltage		COM - 0.3	Vcc + 0.3	
COM	Power ground	Power ground		V <sub>CC</sub> + 0.3	
dVs/dt	Allowable Vs offset supply transien	t relative to COM	_	50	V/ns
P	Package power dissipation @ T <sub>A</sub>	8-Lead SOIC	—	0.625	14/
PD	≤+25°C	14-Lead MLPQ 4x4	_	2.08	W
Dit	Thermal resistance, junction to	8-Lead SOIC	_	200	0000
Rth <sub>JA</sub>	ambient 14-Lead MLPQ 4x4		—	36	°C/W
TJ	Junction temperature		_	150	
Ts	Storage temperature		-55	150	°C
ΤL	Lead temperature (soldering, 10 se	econds)	_	300	1

All supplies are tested at 25 V.

t

## **Recommended Operating Conditions**

For proper operation, the device should be used within the recommended conditions. All voltage parameters are absolute voltages referenced to COM unless otherwise stated in the table. The offset rating is tested with supplies of  $(V_{CC} - COM) = (V_B - V_S) = 15V$ .

Symbol	Definition	Min	Мах	Units
Vcc	Low-side supply voltage	10	20	
V <sub>IN</sub>	Logic input voltage	0	Vcc	
VB	High-side floating well supply voltage	V <sub>S</sub> +10	V <sub>S</sub> + 20	V
Vs	High-side floating well supply offset voltage <sup>†</sup>	COM - 8 <sup>†</sup>	200	v
Vно	Floating gate drive output voltage	Vs	VB	
VLO	Low-side output voltage	СОМ	Vcc	
TA	Ambient temperature	-40	125	°C

Logic operation for VS of -8 V to 200 V. Logic state held for V<sub>S</sub> of -8 V to -V<sub>BS</sub>. Please refer to Design Tip DT97-3 for more details.

## **Static Electrical Characteristics**

 $(V_{CC} - COM) = (V_B - V_S) = 15V$ .  $T_A = 25^{\circ}C$  unless otherwise specified. The V<sub>IN</sub> and I<sub>IN</sub> parameters are referenced to COM. The V<sub>O</sub> and I<sub>O</sub> parameters are referenced to respective V<sub>S</sub> and COM and are applicable to the respective output leads HO or LO. The V<sub>CCUV</sub> parameters are referenced to COM. The V<sub>BSUV</sub> parameters are referenced to V<sub>S</sub>.

Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions
V <sub>BSUV+</sub>	V <sub>BS</sub> supply undervoltage positive going threshold	8.0	8.9	9.8		
V <sub>BSUV</sub> -	V <sub>BS</sub> supply undervoltage negative going threshold	7.4	8.2	9		
V <sub>BSUVHY</sub>	V <sub>BS</sub> supply undervoltage hysteresis	—	0.7		v	
V <sub>CCUV+</sub>	V <sub>CC</sub> supply undervoltage positive going threshold		8.9	9.8	v	
V <sub>CCUV</sub> -	$V_{\text{CC}}$ supply undervoltage negative going threshold	7.4	8.2	9		
V <sub>CCUVHY</sub>	V <sub>CC</sub> supply undervoltage hysteresis	_	0.7			
I <sub>LK</sub>	High-side floating well offset supply leakage	—	—	50		$V_B = V_S = 200V$
I <sub>QBS</sub>	Quiescent V <sub>BS</sub> supply current		45	75	μA	All inputs are in the off state
I <sub>QCC</sub>	Quiescent V <sub>CC</sub> supply current - 3		300	520		
V <sub>OH</sub>	High level output voltage drop, V <sub>BIAS</sub> -V <sub>O</sub>		0.05	0.2	V	$l_{z} = 2 m \Lambda$
V <sub>OL</sub>	Low level output voltage drop, Vo	—	0.02	0.1	v	$I_0 = 2 \text{ mA}$
I <sub>o+</sub>	Output high short circuit pulsed current	200	290	_	mA	$V_O = 0V, V_{IN} = V_{IH}$ PW ≤ 10µs
l <sub>o-</sub>	Output low short circuit pulsed current	420	600	—	ШA	$V_0 = 15V, V_{IN} = V_{IL}$ PW $\leq 10\mu s$
V <sub>IH</sub>	Logic "1" (HIN) & Logic "0" (LIN) input voltage		—		v	Vcc=10V to 20V
VIL	Logic "0" (HIN) & Logic "1" (LIN) input voltage		—	0.8	v	
I <sub>IN+</sub>	Logic "1" Input bias current — 3 10		10	μA	$HIN = 5V, \overline{LIN} = 0V$	
l <sub>IN-</sub>	Logic "0" Input bias current	_	—	5	P'''	$HIN = 0V, \overline{LIN} = 5V$

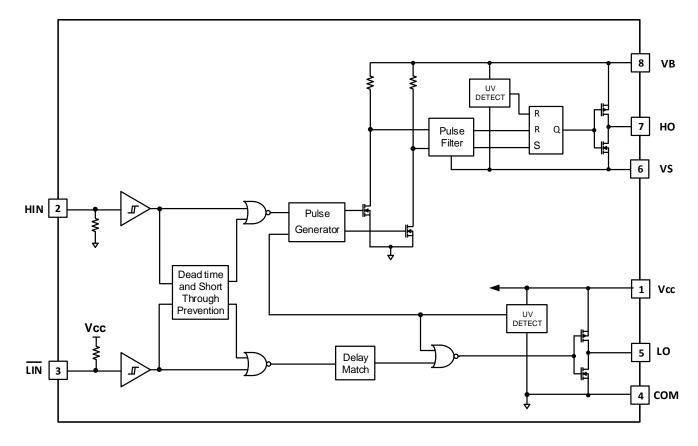
## **Dynamic Electrical Characteristics**

 $V_{CC} = V_B = 15V$ ,  $V_S = COM$ ,  $T_A = 25^{\circ}C$ , and  $C_L = 1000pF$  unless otherwise specified.

Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions
ton	Turn-on propagation delay	—	160	220		Vs = 0V or 200V
toff	Turn-off propagation delay	_	150	220		VS = 0V 0I 200V
t <sub>R</sub>	Turn-on rise time	_	70	170		
t⊨	Turn-off fall time	—	30	90		$V_S = 0V$
МТ	Delay matching time (t <sub>ON</sub> , t <sub>OFF</sub> )	—	_	50	ns	
DT	Deadtime, LS turn-off to HS turn-on & HS turn-on to LS turn-off	400	520	650		
MDT	Deadtime matching time (DT <sub>LO/HO</sub> – DT <sub>HO/LO</sub> )	_	—	30		



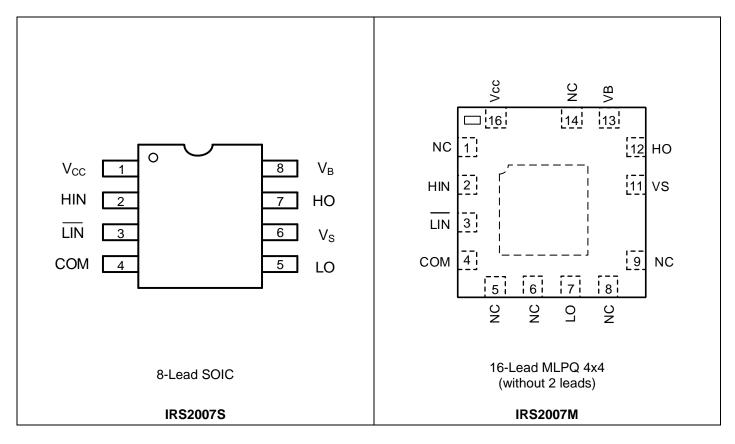
## **Functional Block Diagram**



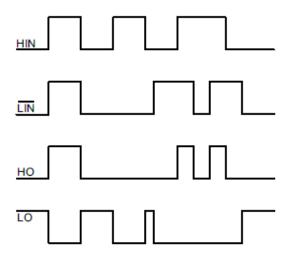
## **Lead Definitions**

Symbol	Description
Vcc	Low-side and logic supply voltage
VB	High-side gate drive floating supply
VS	High voltage floating supply return
HIN	Logic inputs for high-side gate driver output (HO), in phase
LIN	Logic inputs for low-side gate driver output (LO), out of phase
НО	High-side driver output
LO	Low-side driver output
COM	Low-side gate drive return

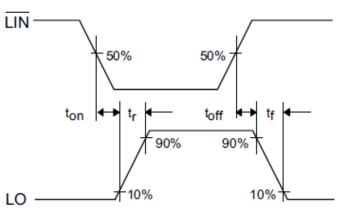
## Lead Assignments



# **Application Information and Additional Details**







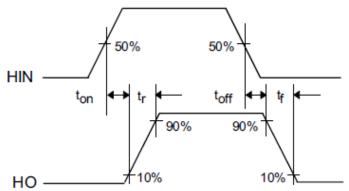
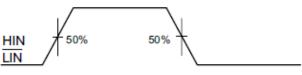


Figure 2. Switching Time Waveform Definitions



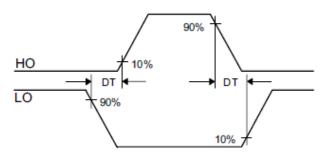
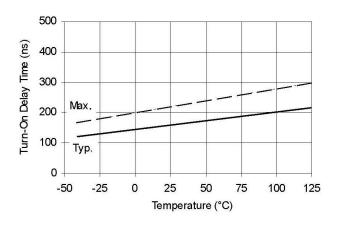


Figure 3. Deadtime Waveform Definitions



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Figure 4A. Turn-On Time vs. Temperature

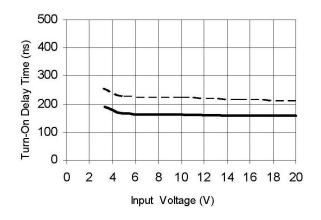


Figure 4C. Turn-On Time vs. Input Voltage

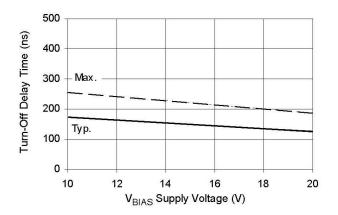


Figure 5B. Turn-Off Time vs. Supply Voltage

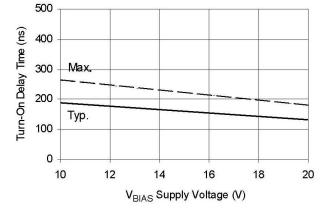


Figure 4B. Turn-On Time vs. Supply Voltage

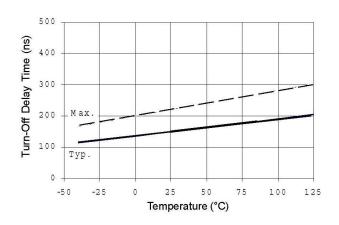


Figure 5A. Turn-Off Time vs. Temperature

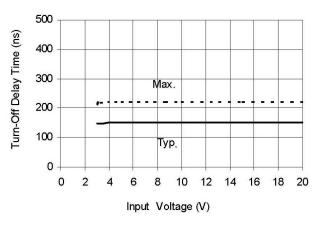


Figure 5C. Turn-Off Time vs. Input Voltage

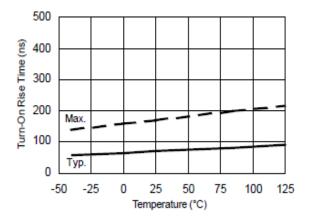


Figure 6A. Turn-On Rise Time vs. Temperature

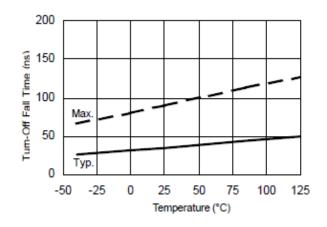


Figure 7A. Turn-Off Fall Time vs. Temperature

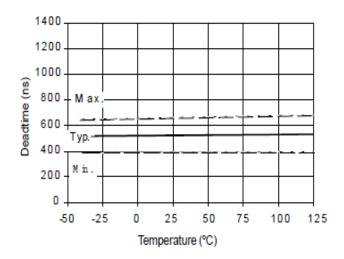
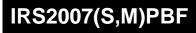


Figure 8A. Deadtime vs. Temperature



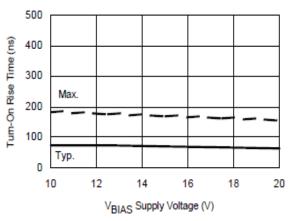


Figure 6B. Turn-On Rise Time vs. Voltage

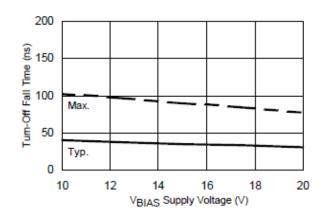


Figure 7B. Turn-Off Fall Time vs. Voltage

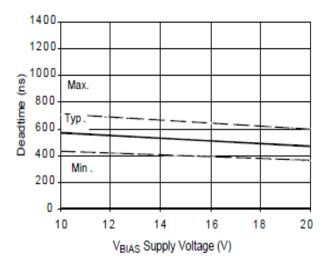


Figure 8A. Deadtime vs. Voltage

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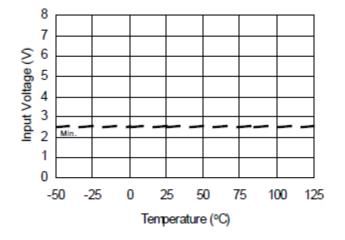
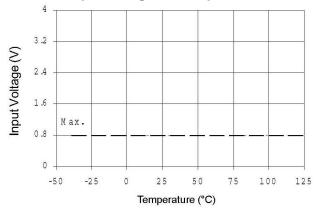
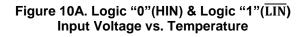
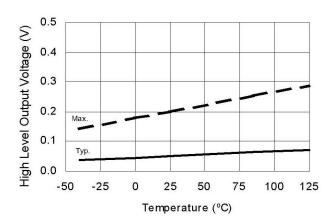


Figure 9A. Logic "1"(HIN) & Logic "0"(LIN) Input Voltage vs. Temperature









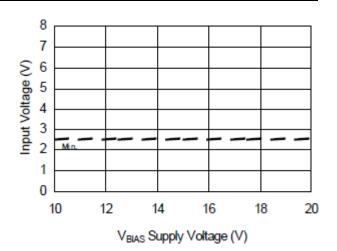


Figure 9B. Logic "1"(HIN) & Logic "0"(LIN) Input Voltage vs. Voltage

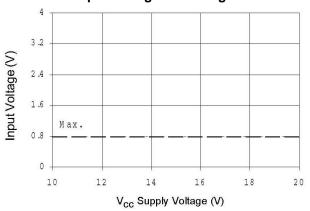


Figure 10B. Logic "0"(HIN) & Logic "1"(LIN) Input Voltage vs. Voltage

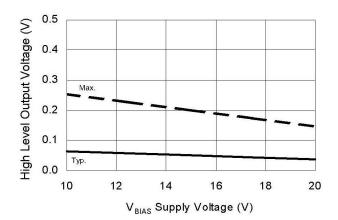
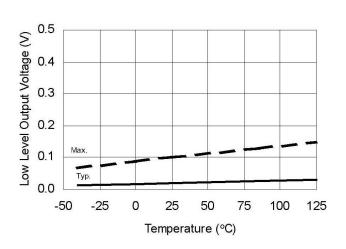


Figure 11B. High Level Output Voltage vs. Supply Voltage



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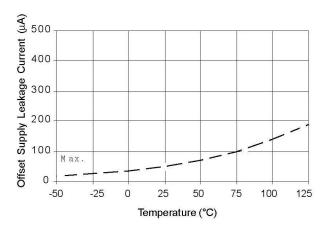
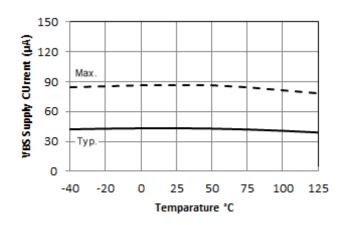


Figure 13A. Offset Supply Current vs. Temperature





0.5 0.4 0.3 0.1 0.2 Max. 10 12 14 16 18 20 V<sub>BIAS</sub> Supply Voltage (V)

Figure 12B. Low Level Output Voltage vs. Supply Voltage

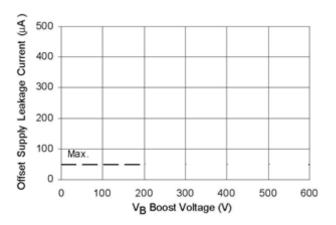


Figure 13B. Offset Supply Current vs. Voltage

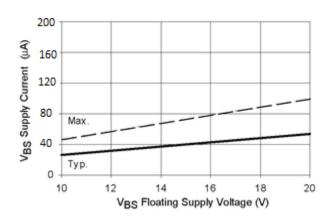
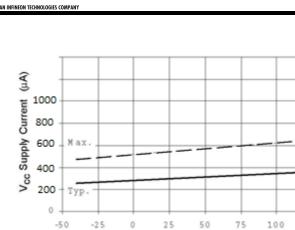


Figure 14B. V<sub>BS</sub> Supply Current vs. Voltage

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Figure 15A. V<sub>cc</sub> Supply Current vs. Temperature

Temperature (°C)

125

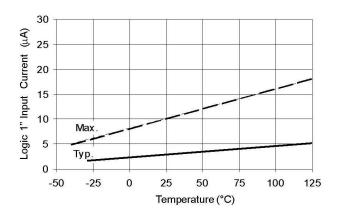


Figure 16A. Logic "1" Input Current vs. Temperature

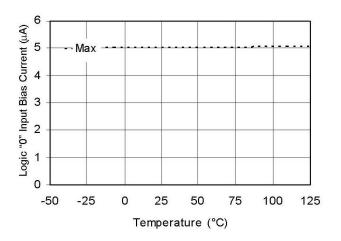


Figure 17A. Logic "0" Input Bias Current

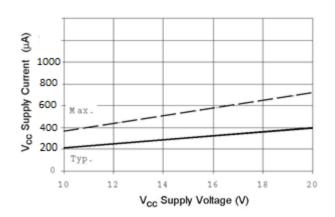


Figure 15B. V<sub>cc</sub> Supply Current vs. Voltage

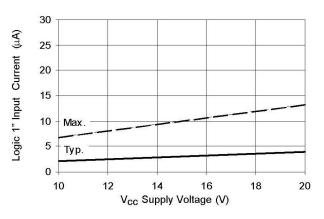


Figure 16B. Logic "1" Input Current vs. Voltage

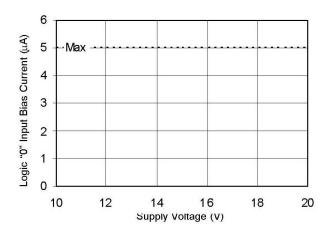
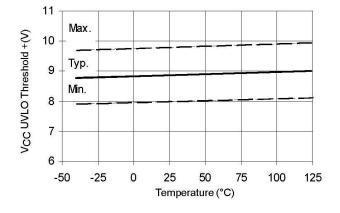
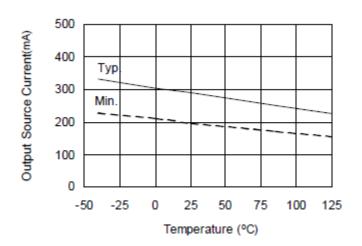


Figure 17B. Logic "0" Input Bias Current

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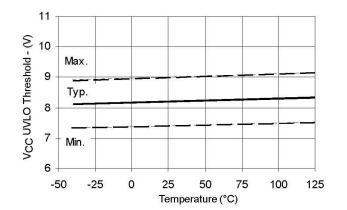


Figure 18B. V<sub>CC</sub>\V<sub>BS</sub> Undervoltage Threshold(-) vs. Temperature

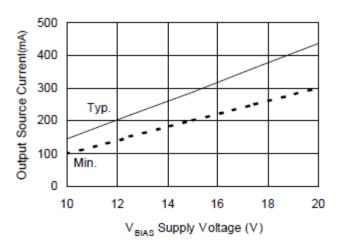


Figure 19B. Output Source Current vs. Supply Current

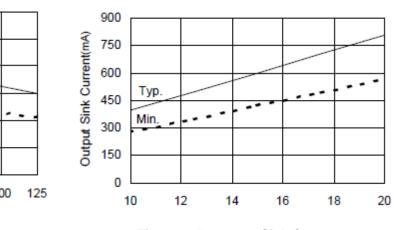
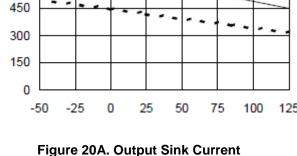


Figure 20B. Output Sink Current vs. Supply Voltage



vs. Temperature

900

750

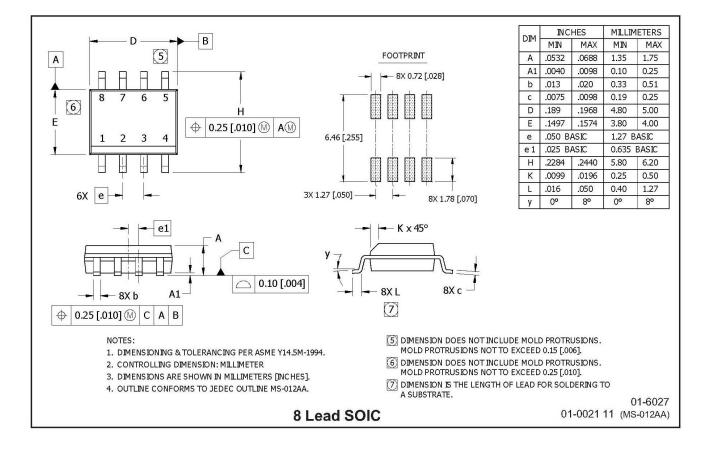
600

Typ.

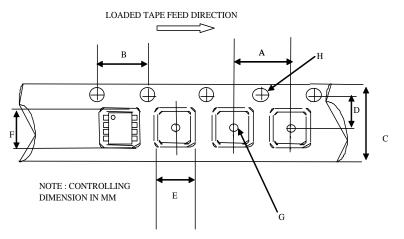
Min.

Output Sink Current (mA)

# Package Details: 8-Lead SOIC

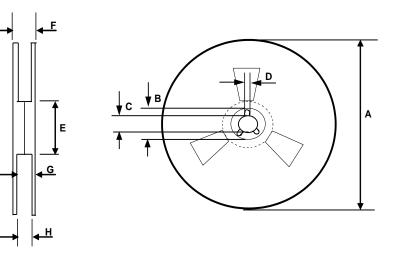


# Tape and Reel Details: 8-Lead SOIC



#### CARRIER TAPE DIMENSION FOR 8SOICN

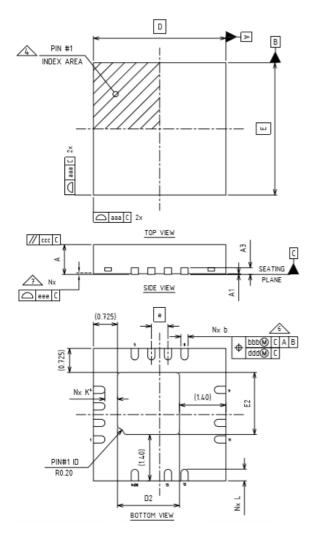
	Metric		Imp	erial
Code	Min	Max	Min	Max
A	7.90	8.10	0.311	0.318
В	3.90	4.10	0.153	0.161
С	11.70	12.30	0.46	0.484
D	5.45	5.55	0.214	0.218
E	6.30	6.50	0.248	0.255
F	5.10	5.30	0.200	0.208
G	1.50	n/a	0.059	n/a
Н	1.50	1.60	0.059	0.062



#### REEL DIMENSIONS FOR 8SOICN

	Metric		Imp	erial
Code	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
В	20.95	21.45	0.824	0.844
С	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	18.40	n/a	0.724
G	14.50	17.10	0.570	0.673
Н	12.40	14.40	0.488	0.566

# Package Details: 14-Lead MLPQ 4x4



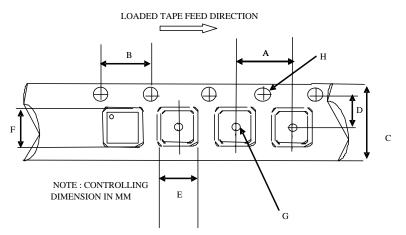
#### NOTE:

- 1. Dimensioning and tolerancing conform to ASME Y14.5-2009.
- 2. All dimensions are in millimeters.
- 3. N is the total number of terminals.
- A. The location of the marked terminal #1 identifier is within the hatched area.
- 5. ND and NE refer to the number of terminals on each D and E side respectively.
- /6 Dimension b applies to the metalized terminal and is measured between 0.15mm and 0.30mm from the terminal tip. If the terminal has a radius on the other end of it, dimension b should not be measured in that radius area.

Coplanarity applies to the terminals and all other bottom surface metalization.

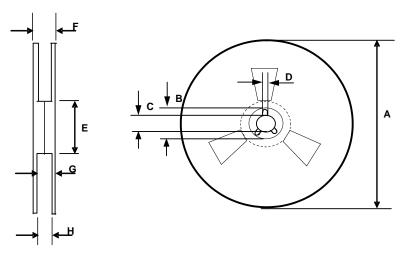
	Dimension Table				
Thickness Symbol	V			NOTE	
mbol	MINIMUM	NOMINAL	MAXIMUM		
A	0.80	0.90	1.00		
A1	0.00	0.02	0.05		
A3		0.20 Ref			
b	0.18	0.25	0.30	6	
D		4.00 BSC			
E		4.00 BSC			
e		0.50 BSC			
D2	1.725	1.875	1.975		
E2	1.725	1.875	1.975		
К	0.20				
L	0.25	0.35	0.45		
aaa		0.05			
bbb		0.10			
CCC	0.10				
ddd	0.05				
eee	0.08				
N	14			3	
ND	SEE FIGURE			5	
NE				,	
NOTES		1, 2			

# Tape and Reel Details: 14-Lead MLPQ 4x4



CARRIER TAPE DIMENSION FOR MLPQ4x4

	Metric		lm	perial
Code	Min	Max	Min	Max
А	7.90	8.10	0.311	0.358
В	3.90	4.10	0.153	0.161
С	11.70	12.30	0.461	0.484
D	5.45	5.55	0.215	0.219
E	4.25	4.45	0.168	0.176
F	4.25	4.45	0.168	0.176
G	1.50	n/a	0.069	n/a
Н	1.50	1.60	0.069	0.063

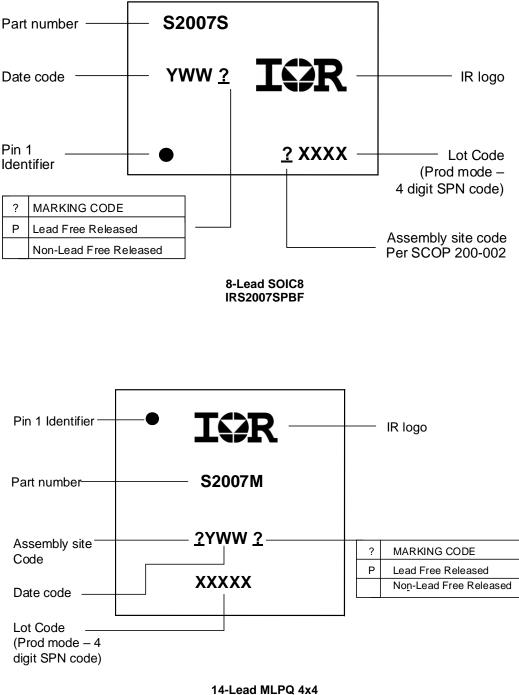


#### REEL DIMENSIONS FOR MLPQ4x4

	Metric		Im	perial
Code	Min	Max	Min	Max
А	329.60	330.25	12.976	13.001
В	20.95	21.45	0.824	0.844
С	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	18.40	n/a	0.724
G	14.50	17.10	0.570	0.673
Н	12.40	14.40	0.488	0.566



## **Part Marking Information**



IRS2007MPBF

## **Qualification Information<sup>†</sup>**

Qualification Level		Industrial <sup>†</sup>	
		Comments: This family of ICs is qualified according to relevant tests of JEDEC47/22/20. IR's Consumer qualification level is granted by extension of the higher Industrial level.	
Moisture Sensitivity Level		8 Lead SOIC	MSL2 <sup>††</sup> , 260°C (per IPC/JEDEC J-STD-020)
		14-Lead MLPQ 4x4	
ESD	Human Body Model	Class 2 (per JEDEC standard JESD22-A114)	
	Machine Model	Class A (per EIA/JEDEC standard EIA/JESD22-A115)	
IC Latch-Up Test		Class I (per JESD78)	
RoHS Compliant		Yes	

According to IR Qualification Requirements for IC products.

† †† Higher MSL ratings may be available for the specific package types listed here. Please contact your Infineon sales representative for further information.



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